Three-term inal transport through a quantum dot in the K ondo regime: C onductance, dephasing and current-current correlations

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We investigate the nonequilibrium transport properties of a three-term inal quantum dot in the strongly interacting lim it. At low tem peratures, a K ondo resonance arises from the antiferrom agnetic coupling between the localized electron in the quantum dot and the conduction electrons in source and drain leads. It is known that the local density of states is accessible through the di erential conductance measured at the (weakly coupled) third lead. Here, we consider the multiterm inal current-current correlations (shot noise and cross correlations measured at two di erent term inals). We discuss the dependence of the current correlations on a number of external parameters: bias voltage, magnetic eld and magnetization of the leads. When the K ondo resonance is split by xing the voltage bias between two leads, the shot noise shows a nontrivial dependence on the voltage applied to the third lead. We show that the cross correlations of the current are more sensitive than the conductance to the appearance of an external magnetic eld. When the leads are ferrom agnetic and their magnetizations point along opposite directions, we not a reduction of the cross correlations. Moreover, we report on the elect of dephasing in the K ondo state for a two-term inal geometry when the third lead plays the role of a ctitious voltage probe.

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I. INTRODUCTION

The K ondo e ect represents a distinguished example of strong many-body correlations in condensed matter physics. Over the last fleen years, much e orthas been made in understanding the implications of the K ondo effect on the scattering properties of phase-coherent conductors. Indeed, the electric transport through a quantum dot connected to two term inals becomes highly correlated when the temperature T is lowered below a characteristic energy scale given by $k_{\rm B}$ $T_{\rm K}$. At equilibrium, the K ondo temperature $T_{\rm K}$ depends on the parameters of the system, i.e., the coupling of the dot to the external leads due to tunneling, the dot onsite repulsion (charging energy) and the position of the resonant level relative to the Ferm i energy $E_{\rm F}$. All of them can be tuned in a controlled way.

In a quantum dot with a su ciently large charging en k_{B} T) and a single energy level well below E $_{\mathrm{F}}$, the dynam ics of the quasilocalized electron becomes almost frozen. Therefore, a quantum dot can be viewed as an articial realization (at the nanoscale) of a magnetic impurity with spin S = 1=2. At very low temperatures (T < T_K), charge uctuations in the dot are suppressed and there arises an e ective antiferrom agnetic interaction between the electrons of the reservoir and the S = 1=2localized m om ent. Remarkably, the measured conductance reaches the maximum value for a quantum channel (2e²=h) and the dot appears to be perfectly transparent when a small voltage eVsd is applied between the source and the drain contacts. Nevertheless, the coherent correlated motion of the delocalized electrons forming the K ondo cloud can be disturbed when either the bias voltage or the temperature are of the order of T_K . In such a case, the many-body wave function of the K ondo state is

expected to su er from dephasing, leading to a decrease in the conductance. This issue has recently attracted a lot of attention^{4,5,6}. In this work, we mim ic in a phenom enological way the e ect of dephasing on the transport properties of a two-term inal quantum dot in the K ondo regime by introducing a ctitious voltage probe.

Now, in the absence of dephasing, the building block of the K ondo resonance is a narrow peak (of width around E_F in the local density of states (LDOS) of the dot. However, full quantum -dot spectroscopy of the LDOS cannot be accomplished with a two-term in al transport setup. In particular, one cannot gain experim ental access to the predicted large voltage induced splitting of the LDOS when $eV_{sd} > k_B T_K \cdot 7^{,8,9,10}$ A way to circum vent this problem is by attaching a third lead, as demonstrated independently by Sun and Guo¹¹ and Lebanon and Schiller. 12 In subsequent laboratory work, De Franceschiet al. 3 observed a split K ondo resonance by employing a slightly modified technique one of the leads was replaced by a narrow wire driven out of equilibrium where left and right moving carriers have dierent electrochem ical potentials.

M otivated in part by the works cited in the preceding paragraph, we are concerned in this paper as well with the nonequilibrium K ondo physics and the uctuations of the current through a quantum dot attached to three leads. As is well known, the investigation of the current-current correlations in mesoscopic conductors has been a fruitful area of research. 14 N evertheless, there are still very scarce applications to strongly correlated systems as the shot noise is a purely nonequilibrium property, and thus more dicult to treat. Hersheld 15 calculates the zero-frequency shot noise using perturbation theory in the charging energy (valid when the Kondo correlations are not large; e.g., at T > T_K). Yam aguchi and

K aw am ura 16 choose the tunneling part of the H am iltonian as the perturbing param eter. D ing and Ng17 study the frequency dependence of the noise by means of the equation-of-m otion m ethod (also reliable for T > T $_{\rm K}$). Meir and Golub 18 perform an exhaustive study of the in uence of bias voltage in the shot noise of a quantum dot in the Kondo regime. Dong and Leil9 discuss the e ect on the shot noise of both external magnetic elds and particle-hole symmetry breaking. A vishai et al. 20 calculate the Fano factor when the leads are s-wave superconductors whereas the case of p-wave superconductivity is treated by A ono et al. 21 The authors 22 exam ine the behavior of the Fano factor at zero tem perature when the form ation of the K ondo resonance competes with the presence of ferrom agnetic leads and spin-ip processes. Lopez et al. 23 m ake use of the two-im purity Anderson Ham iltonian to address the shot noise in double quantum dot system s. To the best of our know ledge, a study of the current uctuations in a multiprobe K ondo im purity is still missing. This is the gap we want to lihere.

In mesoscopic conductors, Buttiker²⁴ shows that the sign of the current cross correlations depends on the statistics of the carriers. It is positive (negative) for bosons (ferm ions) due to statistical bunching (antibunching). This statement is based on a series of assumptions (e.g., zero-im pedance external circuits, spin independent transport, norm altherm alleads). Positive correlations can be found if these conditions are not met (see Ref. 25 for references on this subject). Here, we just mention a few studies based on structures involving a quantum dot. Bagret and Nazarov²⁶ consider a Coulomb-blockaded quantum dot attached to paramagnetic leads whereas the ferrom agnetic case and the spinblockade case are treated by Cottet et al. 27 Borlin et al.28 and Samuelsson and Buttiker29 exam ine the cross correlations of a chaotic dot in the presence of a superconducting lead. In the spin dependent case, Sanchez et al.30 nd that the sign of the cross correlations is a ected by Andreev cross re ections. In the context of quantum com putation, m easuring current cross correlations have been show n³¹ to yield a indirect identi cation of the existence of stream s of entangled particles. Therefore, the cross correlations are a valuable tool in characterizing the electron transport in phase-coherent conductors.

In this work, we consider electron transport through a strongly interacting quantum dot attached to three leads. Section II explains the theoretical fram ework (slave-boson mean-eld theory) we use to compute the conductance and the current-current correlations. We show that the expressions for the cross correlations may be inferred from scattering theory applied to a Breit-Wigner resonance with renormalized parameters. Section III is devoted to the results. First, we assume that the third lead is a ctitious voltage probe and investigate the elect of dephasing with increasing coupling to the probe. Then, we consider that lead as a real probe and relate the differential conductance measured at one electrode with the LDOS of the articial Kondo impu-

rity. We show next that the sign of the cross correlations of the current is negative, as expected from the ferm ionic character of the K ondo correlations at very low temperature. Moreover, we discuss the elect of bias voltage, external magnetic elds, and spin-polarized tunneling in the cross correlations. We mish this section with an investigation of the elect of spin polarized transport in the shot noise. Finally, Sec. IV contains our conclusions.

II. M ODEL

W e m odel the electric transport through the quantum dot using the Anderson H am iltonian in the lim it of large onsite C oulom b interaction U ! 1 . This way we neglect double occupancy in the dot and the H am iltonian is written in terms of the slave-boson language; 32

(ck) is the creation (annihilation) operator describing an electronic state k with spin = f"; #g and energy dispersion "k in the lead = $f1;2;3g, "_0$ is the (spin-dependent) energy level in the dot and Vk is the coupling matrix element. The original dot secondquantization operators have been replaced in Eq. (1) by a combination of the pseudoferm ion operator f and the boson eld b. Hopping o the dot is described by the process c_k^y by f: w henever an electron is annihilated by f , an empty state in the dot is created by b^{y} and then generates an electron with spin in the conduction band of contact . The boson operator (b^{y}) m ay be regarded as a projection operator onto the vacuum (em pty) state of the quantum dot. To make sure that a state with double occupancy is never created, a constraint with Lagrange multiplier is added to the H am iltonian.

The current operator $\hat{\Gamma}$ that yields the electronic ow from lead is given by

$$\hat{\mathbf{I}} = \frac{ie}{\mathbf{N}} \hat{\mathbf{N}} ; \mathbf{H}]; \qquad (2)$$

where $\hat{N}=\frac{P}{k}~c_k^y~c_k$. The general form of the power spectrum of the current uctuations reads 33

 $\hat{I} = \hat{I}$ I describing the uctuations of the current away from its average value $I = h\hat{I}$ i. We are interested in the zero-frequency lim it of S (!). Since the

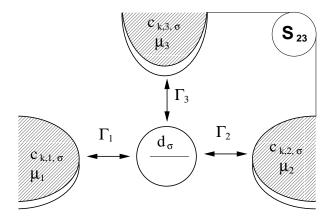


FIG. 1: The system under consideration. The central island is a resonant level coupled to three leads. The level may be shifted through a capacitative coupling to a gate. In the lim it of a vanishingly small capacitance, double occupancy in the dot is forbidden and Kondo e ect can arise. The current current cross correlations are measured between leads 2 and 3.

energy scale $k_B \, T_K$ in typical experiments is of the order of 100 m K, the frequencies should be ! . 2:4 G H z. M oreover, we shallwork at T = 0 (see below) so that the current will uctuate due to quantum uctuations only (we disregard therm all uctuations).

A. Mean-eld approximation

Them ean—eld solution of the H am iltonian (1) consists of considering the e ect of the boson in an averaged way, replacing the true operator b(t) by its expectation value hb(t)i. W ithin this approximation the H am iltonian describes noninteracting quasiparticles with renormalized couplings: V_k pj! V_k . The theory is then suitable for studying the Fermi-liquid xed point of the K ondo problem (i.e., at T $T_{\rm K}$) in which the averaged occupation in the dot is always 1. The dominant uctuations in the system are those associated to spin.

The stationary state of the boson eld is determined from the t! 1 \lim it of its equation of motion using the K eldysh technique for system sout of equilibrium \cdot ^{34,35}

$$X$$

$$\nabla_k G_{f;k}^{<} \quad (t;t) = i \mathcal{D}_{j}^{2}; \quad (4)$$

where $G_{f,k}^{<}$ (t;t) = ihc_{k}^{y} (t)f (t)i is the lead-dot lesser G reen function. Next, we take into account the constraint:

X
$$G_{f;f}^{<}(t;t) = i(1 \quad \cancel{b}_{3}^{2});$$
 (5)

 $G_{f;f}^{<}$ (t;t) = \inf^{y} (t)f (t)i being the dot lesser G reen function. It yields the nonequilibrium distribution function in the dot.

In evaluating the above G reen functions we need the coupling strength given by () = $_k$ y_k f ($"_k$). In the wide band lim it, one neglects the energy dependence of and the hybridization width is taken as = (E_F) for D " D (D is the high-energy cuto). We notice that in the presence of K ondo correlations the lifetime broadening becomes renormalized ! $^{\sim}$ = $_k$ y_k f ($"_k$) and the bare level $"_0$ is shifted to $"_0$ = $"_0$ + . We can now give the full expression of the Fourier-transformed lesser G reen function:

$$G_{f;f}^{<}() = 2i \frac{P}{(v_{0}^{+})^{2} + v_{0}^{-2}};$$
 (6)

where $^{\sim}$ = $^{\rm P}$ is the total hybridization width per spin and f () = () is the Ferm i function at zero tem perature of lead with electrochem ical potential = ${\rm E_F}$ + eV . On the other hand, ${\rm G_f^{<}}_{;k}$ (!) can be cast in term s of ${\rm G_f^{<}}_{;f}$ (!) with the help of the equation of motion of the operators and then applying the analytical continuation rules in a complex time contour. Therefore, we obtain a closed system of two nonlinear equations [Eqs. (4) and (5)] with unknowns ${\rm pf}$ and to be found self-consistently.

From the precedent arguments and Eq. (2) we can easily establish an expression for the expectation value of the electric current:

$$I = \frac{e^{X}}{h}^{Z}$$
 d T ()[f () f ()]; (7)

which has exactly the same transparent form as the Landauer-Buttiker form ula³⁶ in the two channel (one per spin) case applied to a double-barrier resonant-tunneling system:

$$T' \quad () = \frac{4^{\sim} \quad \sim}{(\quad !_{0})^{2} + {}^{\sim} {}^{2}}; \tag{8}$$

which has a simple B reit-W igner lineshape. For the same reason, the quasiparticle density of states is a Lorentzian function centered around the Ferm i level (the Abrikosov-Suhl resonance). This result is expected since we are dealing with a Ferm i liquid but we stress that the physics it contains should not be confused with a noninteracting quantum dot since:

- (i) T depends in plicitly on jof and , and it must then be self-consistently calculated for each set of parameters: contact voltages fV g, magnetic eld $_{Z}$ = " $_{0}$ " " $_{0}$ #, gate voltage " $_{0}$ (V_{g}), and lead magnetization.
- (ii) T is renorm alized by K ondo correlations (as the bare $% \left(1\right) =0$ and $\left(1\right) =0$ are),
- (iii) T has a nontrivial dependence on the bias voltage. All these features give rise to a number of e ects that are not seen in a noninteracting resonant-tunneling diode. There are many instances: regions of negative di erential conductance in the current voltage characteristics of a double quantum dot, 37 a crossover from

K ondo physics to an antiferrom agnetic singlet in the two-im purity problem, 23 an anomalous sign of the zero-bias magnetoresistance, 22 etc. Below, we shall discuss another example without counterpart in a noninteracting B reit-Wigner resonance: When the K ondo peak splits due to a large bias voltage.

B. Current-current correlations

We consider now the current uctuations given by Eq. (3) at zero frequency S $\,$ (0). To simplify the notation we introduce G $_0$ (!) = G $_{\rm f}$; (!) as the dot G reen function. A fter lengthy algebra, we have

$$S (0) = \frac{4e^2}{h} \overset{Z}{d} \sim G_0^{<} G_0^{>} G_0^{a} G_0^{>} f$$

$$+ G_0^{<} G_0^{a} (1 f) G_0^{<} G_0^{r} (1 f) + G_0^{r} G_0^{>} f G_0^{a} G_0^{a} f (1 f)$$

$$G_0^{r} G_0^{r} f (1 f) \frac{1}{2} (G_0^{<} (1 f) G_0^{>} f) [3] : (9)$$

This formula (or variations of it) has been already em ployed in the literature. Weiet al.38 prove it using the Fisher-Lee-Baranger-Stone relation³⁹ to write the scattering matrix elements in terms of the retarded Green function of the dot, G_0^r . Dong and Lei¹⁹ and Lopez et al. 22,23 nd it in Kondo problems within a slave-boson mean-eld fram ework. Actually, in Ref. 23 it is shown that the shot noise in a two-term inal geometry reads T), ie., the well known result for the partition noise but with renormalized transmissions. Souza et al.40 calculate the noise of an ultrasm allm agnetic tunnel junction by means of Eq. (9) within a Hartree-Fock fram ework. In general, we can say that Eq. (9) is consistent within mean-eld theories. However, some caution is needed if one wishes to go beyond a mean-eld level. In deriving Eq. (9), one needs to apply W ick theorem, which is valid only for noninteracting (quasi)-particles. M ore specically, one nds terms that read:

The rst term in the left-hand side corresponds to disconnected diagrams that cancel out the term $h\hat{l}$ $ih\hat{l}$ i of Eq. (3) whereas the second term contributes to Eq. (9). Therefore, the particular H am iltonian has to be cast rst in a quadratic form. Zhu and Balatsky⁴¹ incorrectly state that Eq. (9) takes into account the many-body e ects. A lso, it is not clear how this form ula is inferred within the equation-ofm otion method employed by Lu and Liu. 42

In our case, the mean-eld approximation is known to be the leading term in a 1=N expansion, 43 where N = 2 is the spin degeneracy. Therefore, we neglect the uctuations of both the boson eld (b = 0) and the renormalization of the resonant level (=0), 19,32 which could

be calculated in the next order. This is valid as long as we restrict ourselves to the Ferm i-liquid xed point of the K ondo problem. We are not aware of real 1=N correction calculations of shot noise. Although Meir and Golub¹⁸ perform a noncrossing approximation (NCA), they just substitute the NCA propagators into Eq. (9), with the limitations exposed above.

The current-current correlations can be deduced either using Eq. (9) or using the scattering approach for the multiterm inal case (see Ref. 24). The latter form alism amounts to replacing the bare parameters by the renormalized ones²³. We consider the illustrative case of having dierent electrochemical potentials in two leads,

 Θ (e.g., = 2 and = 3) at zero temperature. We nd

$$S_{23}(0) = \frac{2e^2}{h} X^{Z} d Tr(s_2^y s_2 s_3^y s_3) (f f_a) (f f_b);$$
(11)

where s is the renormalized scattering amplitude of a Breit-Wigner resonance:

$$g = \frac{q}{2i^{2}} = \frac{q}{100}$$

$$g = \frac{q}{100} = \frac{q}{$$

In Eq. (11) the trace Tr(:::) is over spin indices. The Ferm i functions f_a and f_b are arbitrary. ²⁴ C hoosing $f_a = f_b = f_3$, we obtain

$$S_{23}(0) = \frac{2e^2}{h} X Z$$

$$d fT_{12}T_{13}[f_1 f_3]^2$$

$$+ R_{22}T_{32}[f_2 f_3]^2 + 2T_{12}T_{23}[f_1 f_3][f_2 f_3]g; (13)$$

where R $_{22}$ is the re-ection probability (in general R = 1 T). Notice that generally one cannot write the multilead current (current correlations only in terms of transmission probabilities as in Eq. (13). This was rstly pointed out by Buttiker, 44 suggesting the appearance of exchange e ects in noise measurements. Here, since we are dealing with a (renormalized) B reit-W igner resonance, exchange corrections due to phase dierences do not play any role.

For completeness, we give now the form ula for the shot noise, i.e., the current-current correlations measured at the same lead (e.g., lead 1). Following the way of reasoning that led to Eq. (13) we obtain

$$S_{11}(0) = \frac{2e^{2}}{h} X^{2} d fT_{12}R_{11}[f_{1} f_{2}]^{2} + T_{13}R_{11}[f_{1} f_{3}]^{2} + T_{12}T_{13}[f_{2} f_{3}]^{2}g : (14)$$

III. RESULTS

In the following, we present results obtained by self-consistently solving Eqs. (4) and (5) for each bias volt-

age. The rest of param eters is changed in the next subsections. Throughout this work, we have checked that current conservation $(I_1 + I_2 + I_3 = 0)$ is full led.⁴⁵

Tunneling e ects are incorporated at all orders since at equilibrium the K ondo tem perature is found to be

$$k_B T_K^0 = {}^{\sim} = D \exp (-\frac{1}{2} + 2);$$
 (15)

which is clearly a nonperturbative result. In Eq. (15) = $\frac{3}{1}$ is the total hybridization broadening. The reference energy will be always set at $E_F=0$ and the energy cuto is D=100. The bare level is $\mathbf{v}_0=6$, deep below E_F to ensure a pure K ondo regime.

A. Dephasing

Before turning to the determ ination of current cross correlators, we brie y discuss with an application the capabilities of three-term inal setups to illustrate some difcult aspects of the physics of the two-term inal K ondo e ect. As mentioned in the Introduction, we investigate the action of a ctitious voltage probe⁴⁶ (say, lead 3) in order to simulate decoherence e ects on the formation of the K ondo resonance between leads 1 and 2.⁴⁷ These contacts play the role of source and drain, respectively. The voltage probe model⁴⁶ describes decoherence since an electron that is absorbed into the probe looses its coherence. The exiting electron is replaced by an electron (with an unrelated phase) injected by the probe.

At low temperatures the principal source of dephasing is due to quasi-elastic scattering. 48 W e consider then a voltage probe that preserves energy. 49 The current through the voltage probe is zero at every energy . Thus, from Eq. (7) the distribution function at the probe reads

$$f_3() = \frac{T_{13}()f_1() + T_{23}()f_2()}{T_{13}() + T_{23}()}$$
: (16)

We have to insert this result into Eqs. (4) and (5) and solve self-consistently for the hybridization couplings $^{\sim}$ and the resonance level $^{\rm I\!I}_0$ in the presence of quasi-elastic scattering for each value of the applied bias voltage. Then we compute numerically the dierential conductance G = dI=dV_{sd}, where I = I_1 = I_2 and V_{sd} = V_1 V_2.

Figure 2 (a) shows G for dierent values of the coupling to the probe (we set $_2=_1$). For $_3=0$ we obtain the well known zero-bias anomaly, which arises from the formation of the K ondo resonance at $V_{\rm sd}=0$. As $_3$ increases we observe a quenching of the K ondo peak. The degree of the conductance suppression depends on the coupling to the probe. At each bias, $_3$ (which has to be self-consistently calculated) adjusts itself to full the condition of zero net current at each energy . Hence, $_3$ is a phenomenological parameter that includes dephasing processes present in the quantum dot. To see this, we can write down the current through, say, lead 1, using

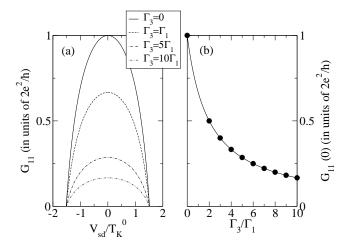


FIG. 2: (a) D i erential conductance G $_{11}$ versus bias voltage V $_1$ as a function of the bare coupling $_3$ to the voltage probe (reservoir 3) for $_1$ = $_2$ and " $_0$ = $_6$. (b) Linear conductance G $_{11}$ (0) showing the reduction of the peak in (a) versus the coupling to the voltage probe. The dots are numerical results where the line corresponds to an analytical formula (see text).

Eqs. (7) and (16):

$$I = \frac{e^{\frac{4^{2}}{1}}}{e^{\frac{1}{1}} + e^{\frac{1}{2}}} Z d A_{0}()[f_{1}() f_{2}()]; \qquad (17)$$

where A_0 (") = Im G_0^r (") = is the LDOS in the dot. Equation (17) has the form of a formula for a two-term inal current⁵⁰ with G_0^r (") = [" $\frac{1}{10}$ + i($\frac{7}{1}$ + $\frac{7}{2}$ + $\frac{7}{3}$)] ¹. It is straightforward to show that a nonzero 3 leads to deviations of Eq. (17) from the unitary lim it.

In Fig. 2(b) we plot the linear conductance G=G ($V_{\rm sd}=0$) as a function of $_{3}=_{1}$ from the results found num erically. At zero bias we can nd from Eq. (17) an analytical expression for the reduction of the peak:

$$G = \frac{2e^2}{h} \frac{2}{2 + \frac{3}{3}} : \tag{18}$$

It is shown in Fig. 2(b) (full line). In the limit of $_3$ = $_1$ 1 a similar expression for the reduction of the peak was found by K am inskiet al., 4 the source of decoherence being an ac voltage applied to the dot level.

B. Multiterm inal conductance

From now on, we consider lead 3 as a real electrode with tunable voltage V_3 . We set $V_3 = V_2 = 0$ and vary the tunneling coupling $_3$. The self-consistent results of Eqs. (4) and (5) are inserted in Eqs. (7) to calculate the di erential conductance through lead 1: $G_{11} = dI_1 = dV_1$. Figure 3 (a) shows G_{11} as a function of V_1 . At $_3 = 0$ the conductance at $V_1 = 0$ achieves the unitary limit as in the two-term inal case. With increasing the coupling to

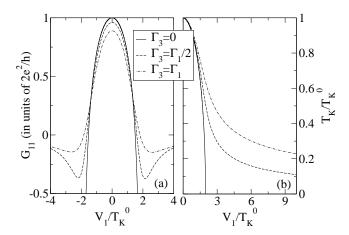


FIG . 3: (a) D i emential conductance G $_{11}$ versus bias voltage V_1 for " $_0$ = $\,$ 6 $\,$ (T $_{\rm K}^{~0}$ = 8 $\,$ 10 3). (b) D ependence of the K ondo tem perature on V_1 .

third lead, G $_{11}$ (0) decreases. For equal tunnel couplings ($_{1}$ = $_{2}$ = $_{3}$ = =3), G $_{11}$ (0) does not reach 1 (in units of $2\mathrm{e}^{2}$ =h) but instead G $_{11}$ (0) = 8=9, in agreement with Ref. 51. This is an immediate consequence of having three leads with identical couplings. Interestingly, the K ondo temperature of Fig. 3 (b) does not vanish abruptly for V_{1} = $2T_{K}^{0}$, as known in the two-term inal case (see the case $_{3}$ = 0). This is an important result as it implies that K ondo correlations survive at large voltages. The e ect is reminiscent of the situation found by A guado and Langreth 37 in tunnel-coupled double quantum dots, though the physical origin is clearly distinct.

C. Sign of the current cross-correlations. Com parison with a noninteracting quantum dot

We now focus on the current-current correlations of the current for $V_3 = V_2 = 0$ and equal couplings $_1 =$ $_2 = _3 = _3$. Later, we shall allow for nonzero voltage di erences between leads 2 and 3. In Fig. 4(a), we show the cross correlator S_{23} (0) obtained from Eq. (13). As expected, S_{23} is zero for $V_1 = 0$ and negative elsewhere. This re ects the ferm ionic nature of the quasiparticles. For comparison, we plot in Fig. 4(b) the corresponding S₂₃ for a noninteracting resonant double-barrier structure with the level at E_F (of course, for "0 = spectrum S23 is always very small as the transmission is). In this case, the physics is governed by the bare coupling .52 On the contrary, in the Kondo problem the dom inating energy scale is T_K . Qualitatively, Fig. 4(a) and 4 (b) look the sam e until V_1 $2T_{\!K}$. The cross correlator in the K ondo case increases with voltage while in the noninteracting case S23 saturates at large voltages. It is easy to show that the saturation value is given by 0:31 (in units of 4é =h). The reason for the increase of S_{23} (0) in Fig. 4(a) is that T_K is voltage dependent unlike the bare, even in the wide-band lim it.

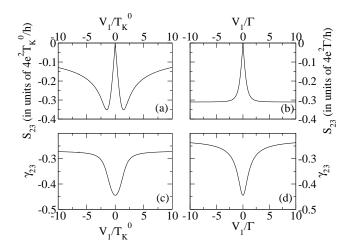


FIG. 4: (a) Current-current cross correlation measured in leads 2 and 3, S_{23} (0), as a function of the bias voltage in the injecting lead, V_1 . K ondo correlations involve an increase of S_{23} (0) for voltages larger than $2T_{\rm K}$. (b) Same as (a) for a noninteracting quantum dot with a resonant level exactly at $E_{\rm F}$. (c) and (d) correspond to the Fano factor $_{23}$ as a function of voltage for the interacting and noninteracting case respectively.

In particular, the current{voltage characteristics shows a region of negative di erential conductance in the K ondo case [see Fig. 3 (a)] whereas it reaches a constant value at large voltages for an noninteracting quantum dot.

To avoid e ects due to m oderate biases, in what follows we shall concentrate on a norm alized S_{23} . We de ne the Fano factor of S_{23} as

$$_{23} = \frac{S_{23}}{2e} :$$
 (19)

If the scattering region were a sim ple barrier of transm ission T, 23 would be simply 1. This number changes when the system under consideration is a quantum dot. In Figs. 4(a) and (b), we plot S_{23} for the Kondo and the noninteracting case, respectively. Their corresponding Fano factors are shown in Figs. 4(c) and (d). We see that $_{23}$ has a minimum at $V_1 = 0$. A nalytically, we nd 4=9 **′** 0:44, which is in excellent agreement with the numerical result. Likewise, we can assess the T_{κ}^{0}). We get $\lim_{n\to\infty} it$ of $_{23}$ at very high voltages (V_1 2=9 **′** 022. As observed, both curves tend to this value, though for a noninteracting quantum dot it is m ore quickly due to the independence of on the bias voltage.

D. E ect of the nonequilibrium splitting on the current-current correlations

Now we turn to an exciting case. Consider the following bias con guration: $V_2 = V_3 \in 0$ and determ ine the dierential conductance G_{11} as a function of V_1 . The case $V_2 = V_3 = 0$ has been treated before. However, due to

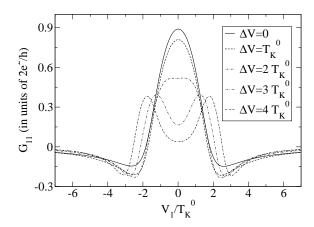


FIG. 5: Dierential conductance G $_{11}\,$ versus bias voltage V_1 for dierent values of the voltage dierence $\,V\,$ $\,$ jV $_2\,$ $\,$ V3 j& $2T_{\kappa}^{\,0}$.

the fact that the boson eld never vanishes, we can study the situation V y_2 y_3 x_3 x_4 y_5 x_5 x_5 x_5 x_6 x_6 x_6 x_6 x_7 x_8 x_8

In Fig. 5 we plot the behavior of the di erential conductance G_{11} . At V = 0 we obtain the zero-bias anomaly of Fig. 3(a). As V increases, G 11 is split T_{κ}^{0} . Both splitting peaks lie at V_{1} at V_2 V_1 V2, i.e., when a pair of electrochem ical potentials are aligned. It is also at those points where the K ondo tem perature is larger. We emphasize that this eect has no sim ilitude in the electronic transport through a noninteracting quantum dot. Still, a mean-eld theory of the Kondo e ect as presented here is able to capture this physics. At the same time that the splitting in G₁₁ develops, the height of the peaks decreases, suppressing the zero-bias anomaly, although not so strongly as in the experim ent¹³ due to the absence of inelastic scattering in this case.

We now use Eq. (13) to calculate the cross correlations between leads 2 and 3. The results are presented in Fig. 6(a). The dependence of S_{23} on voltage is rather asymmetric, hindering the observation of a clear indication due to the voltage induced splitting. The asymmetry is caused by the third term of the right-hand side of Eq. (13), which is not symmetric under the operation V_1 ! V_1 when V_2 > 0. That is the reason why we

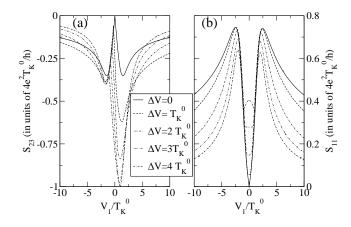


FIG. 6: (a) Cross correlations of the current measured between leads 2 and 3 for the case treated in Fig. 5. (b) Same as (a) for the shot noise in lead 1.

next consider the shot noise in lead 1 S_{11} , which is an even function of the applied V_1 .

In Fig. 6(b) we plot the results of Eq. (14). We observe that S_{11} at $V_1=0$ is nonvanishing with increasing $\,V$, causing a divergence of the Fano factor. This is not related to the K ondo physics but with the fact that the lead 1 at $V_1=0$ acts as a voltage probe with zero in pedance since the net current owing through it is zero. Including the uctuations of the potentials would probably cancel out the divergence. A consequence of K ondo physics is that them inimum at $V_1=0$ turns into a maximum . This occurs when the splitting in G_{11} is sharply formed [see Fig.5].

${\tt E}$. Spin dependent transport and current cross correlations

So far we have assumed spin-independent transport. Let us go back to the bias con guration of Secs. IIIB and IIIC ($V_2 = V_3 = 0$) and focus on the spin-dependent transport properties. It is custom ary in the theoretical studies of spintronic transport to take into account the in uence of external magnetic elds and ferrom agnetic electrodes, among other parameters. Firstly, we shall change the external Zeem an eld and then enable the presence of spin-polarized tunneling.

1. Magnetic eld

We assume that the leads are param agnetic and that the magnetic eld is applied only to the dot, resulting in a Zeem an gap of the bare resonant level: $_{\rm Z}$ = $^{\rm m}_{0"}$ $_{\rm m}$. It is well known that, as a consequence, the K ondo resonance is split when $_{\rm Z}$ $_{\rm K}^{0}$.

Figure 7 (a) shows the di erential conductance G $_{11}$ for di erent values of the Zeem an eld. The conductance is split and quenched with increasing $_{\rm Z}$, as expected. In

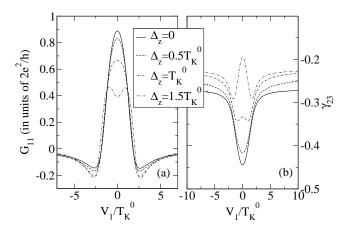


FIG .7: (a) Di erential conductance G $_{11}$ versus V_{11} as a function of the Zeem an term $_{Z}$ for $V_2=V_3=0$. (b) Same as (a) for the Fano factor of the cross correlator, $_{23}$.

Fig. 7 (b), we depict the Fano factor of the cross correlator $_{23}$. It exhibits a very interesting feature. Due to the splitting of the K ondo peak, the minimum of the cross correlator at $V_1=0$ becomes a local maximum, resulting from the suppression of the K ondo e ect. However, this change occurs before the splitting of the conductance G_{11} . Therefore, measuring the shot noise provides new information in this case. The presence of the splitting would be detected in an experiment more precisely by means of the shot noise. The underlying reason is that the form of Eq. (13) diers from that of the current which is basically proportional to T_{12} alone, see Eq. (7). As a result, the width of the G_{11} resonance is a bit larger than the $_{23}$ antiresonance and the former is then more robust than the latter against the application of magnetic elds.

2. Ferrom agnetic leads

There has recently been considerable debate about the in uence of ferrom agnetic leads in the K ondo physics of a quantum dot. 54,55,56,57 In the preceding subsection, it was clear that an external magnetic eld alters the real part of the quantum -dot self-energy, breaking the spin degeneracy. In the case of spin polarized tunneling, the situation is more subtle. 57 When the magnetic moments of the contacts are aligned along the sam e direction, the density of states of the localized electron undergoes a splitting if particle-hole symmetry is broken. 58 Recent transport experim ents with C_{60} molecules and carbon nanotubes have addressed this regim e. 59,60 However, in our case the dot is in the strong coupling lim it and the K ondo e ect is pure in the sense that no charge uctuations are allowed. Thus, no splitting is expected in the di erential conductance.

In Fig. 8(a), we show the cross correlator $_{23}$ for different values of the lead magnetization in the parallel

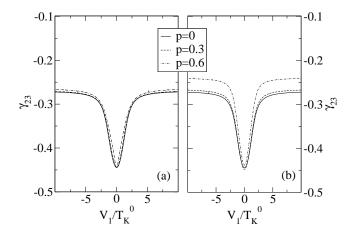


FIG. 8: Fano factor of the cross correlator, $_{23}$ vs $V_1=T_{\text{K}}^0$ for di erent lead m agnetization when $V_2=V_3=0$. (a) Parallel alignment between the magnetizations of the leads with spin polarizations: $p_1=p_2=p_3=p$. (b) Antiparallel case with $p_1=p_2=p_3=p$.

case. This means that $p_1 = p_2 = p_3 = p$, where p is the spin polarization of lead . Ferrom agnetism in the leads arises through spin-dependent densities of states "k). Hence, the linew idths become () =spin dependent: = (1 p), where + (-) corresponds to up (down) spins. We prefer to restrict p to small values as strong magnetizations would require a proper treatment of the reduction of the bandwidth D. We observe that 23 is rather insensitive to changes in p in the same fashion as G $_{11}$ is in the Ferm i-liquid xed point²². Only at moderate polarizations (p = 0:6) we see that the dip in 23 gets narrower because the K ondo tem perature decreases as p increases 56,57 . In addition, 23 is always negative in contrast to the results obtained in the Coulomb blockade regime where 23 can take positive values²⁷. When the spin-ip scattering rate is smaller than the tunneling rate, 23 can be positive. However in the Kondo regime this condition is never met since the rate of spin ip scattering $1=T_K$ is always much longer than the tunneling rate 1= . Figure 8 (b) is devoted to the antiparallel case: $p_1 =$ p₂ = $p_3 = p$. A coordingly, 23 is lifted with increasing lead polarization since the conductance peak decreases with increasing p (roughly, with a factor 1 $p^2)^{22}$.

IV. CONCLUSION

In sum mary, we have investigated the K ondo temperature, the dierential conductance and cross correlations of the current when three leads are coupled to an articial K ondo impurity in the Ferm i-liquid xed point of the in nite-U Anderson H am iltonian (T T_K). We have performed a systematic study of the properties of the cross correlators when dc bias, Zeem an splittings, and ferrom agnetic leads in uence the nonequilibrium transport through the quantum dot. Our most relevant result

is the behavior of the shot noise when there arises a voltage induced splitting in the quantum dot.

In addition, we have studied the current of a two-term inal quantum dot attached to a voltage probe. We have shown that increasing the coupling with the probe induces a quenching of the K ondo peak. Despite the simplicity of this approach, it gives rise to results that are in agreement with more sophisticated models, 4,61 though the precise processes responsible for the decoherence need still to be derived from a microscopic model.

We have not exhausted all the possibilities that the model o ers and more complicated geometries with appealing results can be envisaged. One could address the situation with two injecting and two receiving leads, which could give rise to Hanbury Brown-Twiss-like e ects. 62 We expect that phase related exchange terms will arise especially at higher temperatures (T > $T_{\rm K}$), when the singlet state between the localized spin and the conduction electrons is not yet well formed. We believe that in the presence of spin-polarized couplings due to

ferrom agnetic leads, bunching e ects will be enhanced. 63

Im provem ents of the model should go in the direction of including uctuations of the boson eld and of the renormalized level. However, we do not expect large deviations from the results reported here when T $_{\rm K}$. These uctuations will evidently become important as temperature approaches $T_{\rm K}$. Experimentally, our predictions can be tested with present technology such as G aAs quantum dots 13 or carbon-nanotube nanostructures. 64

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